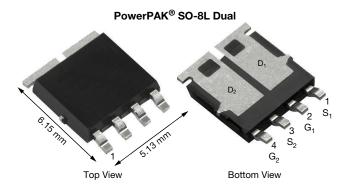
## SQJB42EP

www.vishay.com

**Vishay Siliconix** 

# Automotive Dual N-Channel 40 V (D-S) 175 °C MOSFET



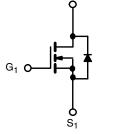
PRODUCT SUMMARY	
V <sub>DS</sub> (V)	40
$R_{DS(on)}$ ( $\Omega$ ) at $V_{GS}$ = 10 V	0.0095
I <sub>D</sub> (A) per leg	30
Configuration	Dual
Package	PowerPAK SO-8L

### FEATURES

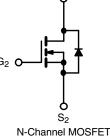
- TrenchFET<sup>®</sup> power MOSFET
- AEC-Q101 qualified
- 100 %  $R_q$  and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



RoHS COMPLIANT HALOGEN FREE



D



 $D_2$ 

N-Channel MOSFET

ABSOLUTE MAXIMUM RATIN	<b>GS</b> (T <sub>C</sub> = 25 °C, unless	otherwise noted	i)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V <sub>DS</sub>	40	V	
Gate-source voltage		V <sub>GS</sub>	± 20	V	
Continuous drain current <sup>a</sup>	T <sub>C</sub> = 25 °C		30		
Continuous drain current 4	T <sub>C</sub> = 125 °C	Ι <sub>D</sub>	30		
Continuous source current (diode conduction) <sup>a</sup>		I <sub>S</sub>	30	А	
Pulsed drain current <sup>b</sup>		I <sub>DM</sub>	120		
Single pulse avalanche current		I <sub>AS</sub>	25		
Single pulse avalanche energy	L = 0.1 mH	E <sub>AS</sub>	31	mJ	
Movimum nouver dissinction b	$T_{\rm C} = 25 ^{\circ}{\rm C}$	P	48	10/	
Maximum power dissipation <sup>b</sup>	T <sub>C</sub> = 125 °C	P <sub>D</sub>	16	W	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C	
Soldering recommendations (peak temperature) <sup>d, e</sup>			260	-0	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount <sup>c</sup>	R <sub>thJA</sub>	85	°C/W
Junction-to-case (drain)		R <sub>thJC</sub>	3.1	C/W

#### Notes

a. Package limited.

b. Pulse test; pulse width  $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%.$ 

c. When mounted on 1" square PCB (FR4 material).

d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

S16-2457-Rev. A, 05-Dec-16 1

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SQJB42EP

PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static				•	•	•	
Drain-source breakdown voltage	V <sub>DS</sub>	V <sub>GS</sub> =	= 0 V, I <sub>D</sub> = 250 μA	40	-	-	V
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	- V <sub>GS</sub> , I <sub>D</sub> = 250 μΑ	2.5	3.0	3.5	v
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	0 V, $V_{GS} = \pm 20$ V	-	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V	-	-	1	
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V, T <sub>J</sub> = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	150	
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = 10 V	$V_{DS} \ge 5 V$	25	-	-	Α
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 10 A	-	0.0079	0.0095	
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}$	I <sub>D</sub> = 10 A, T <sub>J</sub> = 125 °C	-	-	0.0134	Ω
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 10 A, T <sub>J</sub> = 175 °C	-	-	0.0160	
Forward transconductance <sup>b</sup>	9 <sub>fs</sub>	V <sub>DS</sub>	= 15 V, I <sub>D</sub> = 10 A	-	37	-	S
Dynamic <sup>b</sup>							
Input capacitance	C <sub>iss</sub>			-	1080	1500	
Output capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 25 V, f = 1 MHz	-	780	1100	pF
Reverse transfer capacitance	C <sub>rss</sub>	1		-	30	45	
Total gate charge <sup>c</sup>	Qg			-	17	30	
Gate-source charge <sup>c</sup>	$Q_gs$	$V_{GS} = 10 V$	$V_{DS} = 20 \text{ V}, \text{ I}_{D} = 2 \text{ A}$	-	5	-	nC
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>	1		-	3	-	
Gate resistance	Rg		f = 1 MHz	0.3	0.64	1	Ω
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>			-	13	25	
Rise time <sup>c</sup>	t <sub>r</sub>	V <sub>DD</sub> -	= 20 V, R <sub>L</sub> = 10 Ω	-	4	10	
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>	I <sub>D</sub> ≅ 2 A, '	$V_{GEN}$ = 10 V, $R_g$ = 1 $\Omega$	-	21	40	ns
Fall time <sup>c</sup>	t <sub>f</sub>	1		-	18	30	
Source-Drain Diode Ratings and Charac	cteristics <sup>b</sup>						
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	120	Α
Forward voltage	V <sub>SD</sub>	I <sub>F</sub> =	10 A, V <sub>GS</sub> = 0 V	-	0.83	1.2	V
Body diode reverse recovery time	t <sub>rr</sub>			-	44	90	ns
Body diode reverse recovery charge	Q <sub>rr</sub>		$\Lambda di/dt = 100 \Lambda/cc$	-	47	100	nC
Reverse recovery fall time	t <sub>a</sub>	IF = 5	A, di/dt = 100 A/µs	-	23	-	
Reverse recovery rise time	t <sub>b</sub>			-	23	-	ns
Body diode peak reverse recovery current	I <sub>RM(REC)</sub>			-	-2	-4	Α

Notes

a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

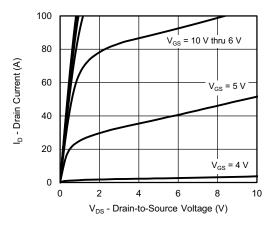
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

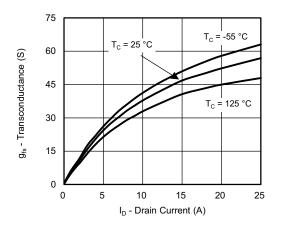
2



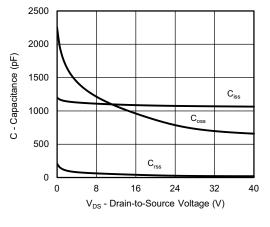
## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



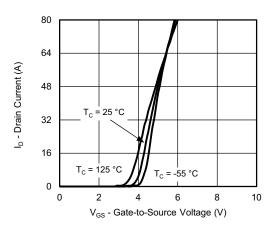
**Output Characteristics** 



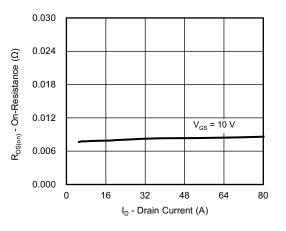
Transconductance



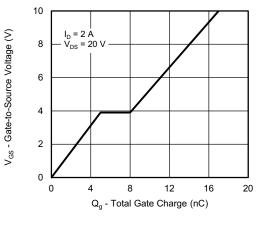
Capacitance



Transfer Characteristics



**On-Resistance vs. Drain Current** 



Gate Charge

S16-2457-Rev. A, 05-Dec-16

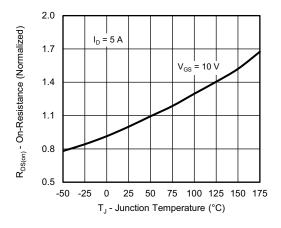
3

Document Number: 75345

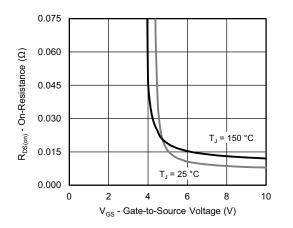
For technical questions, contact: <u>automostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



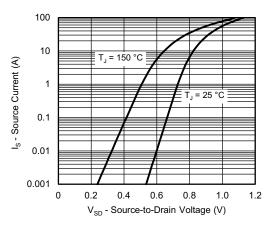
### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



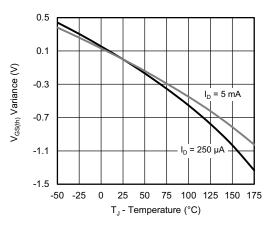
**On-Resistance vs. Junction Temperature** 

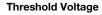


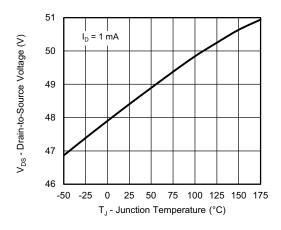
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



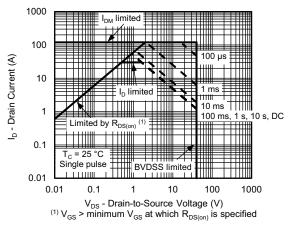




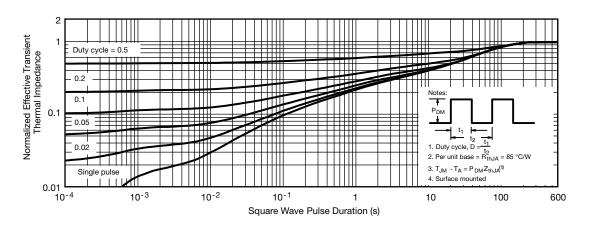
Drain Source Breakdown vs. Junction Temperature



### **THERMAL RATINGS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

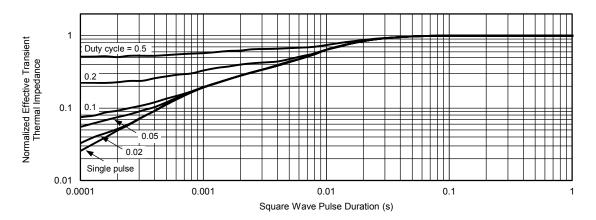


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Document Number: 75345

### **THERMAL RATINGS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



#### Normalized Thermal Transient Impedance, Junction-to-Case

#### Note

• The characteristics shown in the two graphs

S16-2457-Rev. A, 05-Dec-16

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?75345">www.vishay.com/ppg?75345</a>.

6









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# **Package Information**



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DIM.	MILLIMETERS			INCHES			
	MIN.	NOM.	MAX. MIN.		NOM.	NOM. MAX.	
А	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
К		0.51			0.020		
W	0.23			0.009			
W1	0.41			0.016			
W2	2.82			0.111			
W3		2.96		0.117			
θ	0°	-	10°	0°	-	10°	

Note

• Millimeters will govern



#### **RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL**



Recommended Minimum Pads Dimensions in mm (inches) Keep-out 6.75 (0.266) x 7.75 (0.305)

Revision: 07-Feb-12



Vishay

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